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16V Low Cost, High Performance CMOS Rail-to-Rail Operational Amplifiers

Preliminary Technical Data

FEATURES

Low Offset Voltage: 75 µV max Low Input Bias Currents 1pA Max Single-Supply Operation: 5 to 16 Volts Dual-Supply Operation: +/- 2.5 to +/-8 Volts Low Noise: 10 nV/√Hz Wide Bandwidth: 4 MHz Unity Gain Stable

APPLICATIONS

Multi-pole Filters Sensors Medical Equipment Consumer Audio Photodiode amplification ADC driver

GENERAL DESCRIPTION

The AD8661, AD8662 and AD8664 are single, dual and quad rail-to-rail output single supply amplifiers that use Analog Devices' patented DigiTrim® trimming technique to achieve low offset voltage. The AD8661 family features an extended operating range with supply voltages up to 16 V. They also feature low input bias currents, wide signal bandwidth, and low input voltage and current noise.

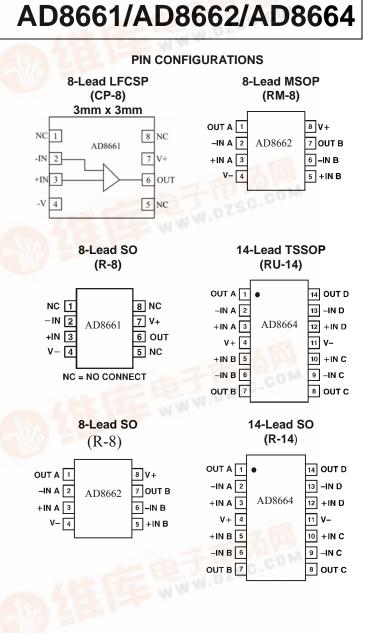
The combination of low offsets, very low input bias currents, and wide supply range make these amplifiers useful in a wide variety of applications normally associated with much higher priced JFET amplifiers. Systems utilizing high impedance sensors, such as photo-diodes benefit from the combination of low input bias current, low noise, low offset and bandwidth. The wide operating voltage range matches today's high performance ADCs and DACs. Audio applications and medical monitoring equipment can take advantage of the high input impedance, low voltage and current noise, wide bandwidth and the lack of "popcorn" noise (found in many other low input bias current amplifiers).

The AD8661, AD8662 and AD8664 are specified over the extended industrial (-40° to +125°C) temperature range. The AD8661, single, is available in the tiny 8-lead LFCSP (MO-220) 3mm x 3mm and 8-lead SOIC package. The AD8662, dual, is available in the 8-lead micro-SOIC and narrow SOIC surface mount packages. The AD8664, quad, is available in 14-lead TSSOP and narrow 14-pin SOIC packages.

LFCSP, MSOP and TSSOP versions are available in tape and reel only.

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Preliminary Technical Data AD8661/AD8662/AD8664

ELECTRICAL CHARACTERISTICS (V_{S} =+5.0V, V_{CM} = $V_{S}/2$, T_{A} =+25°C unless otherwise

noted)						
Parameter	Symbol	Conditions	Min	Тур	Max	Units
INPUT CHARACTERISTICS						
Offset Voltage	V _{OS}	$V_{SY} = 8V, V_{CM} = 3V$			75	μV
		$V_{CM} = 0.1V$ to 3.0V		30	300	μV
		-40°< T _A < +85°C			650	μV
		-40°< T _A < +125°C			750	μV
Input Bias Current	I _B			0.3	1	рА
	D	-40°< T _A < +85°C			50	pA
		-40°< T _A < +125°C			300	pA
Input Offset Current	I _{OS}			0.2	TBD	pА
		-40°< T _A < +85°C			20	pА
		-40°< T _A < +125°C			75	pА
Input Voltage Range			tbd		3.0	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = 0.1V$ to 3.0V	80	95		dB
Large Signal Voltage Gain	A _{VO}	$R_L = 10 \text{ k}\Omega \text{ V}_0 = 0.5 \text{V}$ to 4.5V	70	100		V/mV
Offset Voltage Drift	$\Delta V_{OS} / \Delta T$			3	10	μV/°C
OUTPUT CHARACTERISTICS						
Output Voltage High	V _{OH}	$I_L = 1mA$	4.80	4.85		V
		I _L = 10mA	4.80	4.85		V
		-40°C < T _A < +125°C	4.75			V
Output Voltage Low	V _{OL}	$I_{L} = 1 m A$		60	120	mV
	V _{OL}	$I_{L} = 1mA$		60	120	mV
	02	-40°C < T _A < +125°C			150	mV
Output Current	I _{OUT}			±19		mA
Closed Loop Output Impedance	Z _{OUT}	f=1 MHz, $A_V = 1$		65		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{S} = 5 V$ to 16 V	80	95		dB
Supply Current/Amplifier	I _{SY}	$V_{O} = 0V$		1.2	1.8	mA
		-40°< T _A < +125°C			2.0	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	R _L =10 kΩ		3		V/μs
Settling Time	t _s	To 0.1%, 0 V to 1V step		<1		μS
Gain Bandwidth Product	GBP			4		MHz
Phase Margin	Øo degrees	C _L = 15 pF			60	
NOISE PERFORMANCE						
Peak-to-Peak Noise	e _n p-p	f=0.1Hz to 10 Hz		2.5		μV p-p
Voltage Noise Density	e _n	f=1kHz		12		nV/√Hz
Voltage Noise Density	e _n	f=10kHz		10		nV/√Hz
Current Noise Density	i _n	f=1kHz		0.1		pA/√Hz

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ELECTRICAL CHARACTERISTICS (V_S=±8.0V, V_{CM} = 0, T_A=+25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Max	Units
INPUT CHARACTERISTICS						
Offset Voltage	V _{OS}	$V_{SY} = 8V, V_{CM} = 3V$			75	μV
		$V_{CM} = -8.1V$ to +6.0V		30	300	μV
		-40°< T _A < +85°C			650	μV
		-40°< T _A < +125°C			750	μV
Input Bias Current	I _B			0.3	1	pА
		-40°< T _A < +85°C			50	pА
		-40°< T _A < +125°C			300	pА
Input Offset Current	I _{OS}			0.2	TBD	pА
		-40°< T _A < +85°C			20	pА
		-40°< T _A < +125°C			75	pА
Input Voltage Range			tbd		6	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -8.1V$ to $+6.0V$	80	95		dB
Large Signal Voltage Gain	A _{VO}	R_L =10 k Ω V _O = -7.5V to+7.5V	70	85	10	V/mV
Offset Voltage Drift	$\Delta V_{OS} / \Delta T$			3	10	μV/°C
OUTPUT CHARACTERISTICS	M	1 1	7.00	7.05		N
Output Voltage High	V _{OH}	$I_L = 1mA$	7.90 7.6	7.95		V V
		I _L = 10mA -40°C < T _A < +125°C	7.6 7.4	7.7		V
		$-40 C < T_A < +125 C$	7.4			V
Output Voltage Low	V _{OL}	$I_{L} = 1 m A$		-7.97	-7.93	mV
	OL	$I_{\rm I} = 10 {\rm mA}$		-7.8	-7.7	mV
		-40°C < T _A < +125°C			-7.5	mV
Output Current	I _{OUT}			±140		mA
Closed Loop Output Impedance	Z _{OUT}	$f=1 \text{ MHz}, A_V = 1$		45		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{\rm S} = 5V$ to 16V	80	95		dB
Supply Current/Amplifier	I _{SY}	$V_{O} = 0V$		1.5	1.8	mA
		-40°< T _A < +125°C			2.0	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 10 \text{ k}\Omega$		3		V/μs
Settling Time	t _s	To 0.1%, 0 V to 1V step		<1		μs
Gain Bandwidth Product	GBP ~			4		MHz
Phase Margin	Øo	C _L = 15 pF		60		degrees
NOISE PERFORMANCE	0.0-	f 0 111= to 10 11=		25		
Peak-to-Peak Noise Voltage Noise Density	e _n p-p	f=0.1Hz to 10 Hz		2.5		µV p-p nV/√Hz
•	e _n	f=1kHz		12		nV/√Hz
Voltage Noise Density	e _n :	f=10kHz		10		
Current Noise Density	i _n	f=1kHz		0.1		pA/√Hz

AD8661/AD8662/AD8664

ABSOLUTE MAXIMUM RATINGS¹

Supply voltage+18V
Input Voltage
Differential Input Voltage±18V
Output Short-Circuit Duration to Gnd ² Observe Derating Curves
Storage Temperature Range
R, CP, RM, RU Package65°C to +150°C
Operating Temperature Range
AD8661/AD8662/AD866440°C to +125°C
Junction Temperature Range
R, CP, RM, RU Package65°C to +150°C
Lead Temperature Range (Soldering, 60 Sec)+300°C

Package Type	θJA	θJC	Units
8-Pin LFCSP (CP)			°C/W
8-Pin microSOIC (RM)	210	45	°C/W
8-Pin SOIC (R)	158	43	°C/W
14-Pin SOIC (R)	120	36	°C/W
14-Pin TSSOP (RU)	180	35	°C/W

NOTES

 1 Absolute maximum ratings apply at 25°C, unless otherwise noted.

 2 θ_{JA} is specified for the worst-case conditions, i.e., θ_{JA} is specified for device soldered in circuit board for surface mount packages.

ORDERING GUIDE

	Temperature	Package	Package	Branding
Model	Range	Description	Option	Information
AD8661ACP	-40°C to +125°C	8-Pin LFCSP	CP-8	
AD8661ARZ	-40°C to +125°C	8-Pin SOIC	R-8	
AD8662ARMZ	-40°C to +125°C	8-Pin micro-SOIC	RM-8	
AD8662ARZ	-40°C to +125°C	8-Pin SOIC	R-8	
AD8664ARZ	-40°C to +125°C	14-Pin SOIC	R-14	
AD8664ARUZ	-40°C to +125°C	14-Pin TSSOP	RU-14	

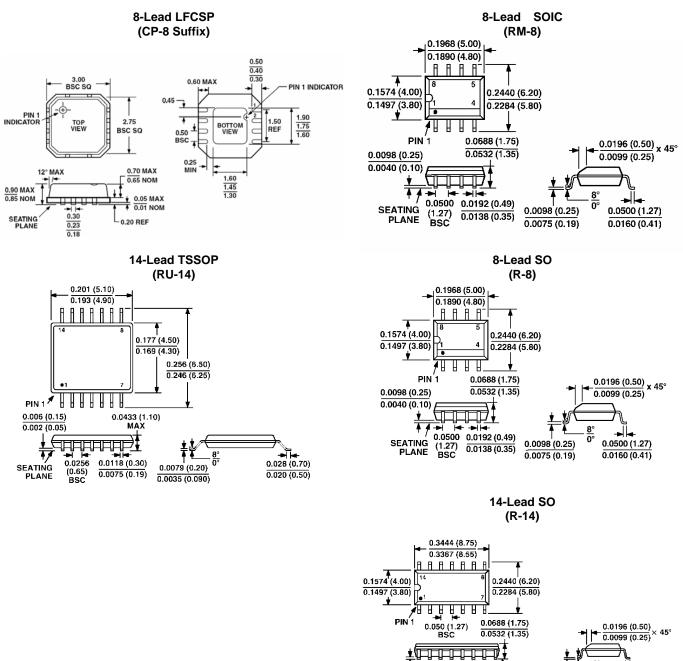
CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 1500 V readily accumulate on the human body and test equipment and can discharge without detection. Although this device features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high-energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



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OUTLINE DIMENSIONS

0.0500 (1.27)

0.0160 (0.41)

ō

0.0075 (0.19)

0.0192 (0.49) 0.0138 (0.35) SEATING PLANE 0.0099 (0.25) 0.0075 (0.19)

0.0098 (0.25)

0.0040 (0.10)